



2m TRANSVERTER

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FEATURES

- 1 TV-502 is designed to be used in combination with TS-520 for 144 MHz operation.
- 2 Operates in the frequency range from 144.0 MHz to 145.7 MHz, or up to 146.0 MHz by installing additional X'tal oscillating elements.
- 3 Amplification type ALC system is employed. ALC voltage feed back to TS-520 minimizes the distortion caused by overdriving, assuring quality transmission.
- 4 All-solid-state configuration with FET employed in major circuits.
- 5 TV-502 provides maximum enjoyment of 144 MHz SSB mobile operation, when connecting TS-520 with DS-1.

6 Enjoyable excellent operation performance of TS-520 on 144 MHz band by connecting to TS-520.

- 7 Receiving antenna circuit incorporates highly sensitive tuning circuit to minimize radio interference.
- 8 Unique, functional design perfectly matches the styling of TS-520, VFO-520 and SP-520.
- 9 With minor modification of wiring, changeover between HF and VHF is effected by simply manipulating the Power Switch of TV-502.

SPECIFICATIONS

TRANSMITTING/RECEIVING FREQUENCY	144 \sim 145.7 MHz	
	$145.0 \sim 146.0~{ m MHz}$	z (option)
INPUT/OUTPUT IF FREQUENCY	$28.0\sim29.7~{ m MHz}$	
TYPE OF EMISSION	SSB (A3J)	
	CW (A1)	
RATED OUTPUT	8W (AC operation)	
ANTENNA INPUT/OUTPUT IMPEDANCE		
UNWANTED RADIATION	Less than –60 dB	
RECEIVING SENSITIVITY		/N 10 dB
IMAGE RATIO		
IF REJECTION		
FREQUENCY STABILITY		during $1 \sim 60$ min after power switch is
	ON and within 150	Hz (per 30 min) thereafter.
POWER CONSUMPTION	AC 220/120 V	
	Transmission	50W max
	Reception	12W max
	DC 13.8 V	
	Transmission	2A max
	Reception	0.4A max
POWER REQUIREMENT	AC 220/120 V	
	DC 12 ~ 16 V (stan	dard voltage 13.8 V)
SEMICONDUCTOR	FET	5
	Transistor	15
	Diode	19
DIMENSIONS	6-9/16" (168 mm) v	vide x 5-15/16'' (153 mm) high x 13-1/8''
	(336 mm) deep	
WEIGHT	11.5 lbs. (5.2 kg)	

FINAL TRANSISTOR SPECIFICATION (2SC1242A ABSOLUTE MAX. RATINGS)

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V _{CBO} :	35 V
V _{CEO} :	18 V
V _{EBO} :	3.5 V
I _C :	4.5 A
P _C :	30 W (T _C = 25° C)
Tj:	175°C
T _{stg} :	$-65 \sim 175^{\circ}$ C

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CIRCUIT DESCRIPTION



Fig. 1 TV-502 Block Diagram

Fig. 1 shows the block diagram of TV-502.

RF UNIT (X44-1120-00)

This unit is composed of an RF amplifier and mixer for reception, a balanced type mixer ($2SK19 \times 2$) and 2-stages RF amplifier for transmission, and a final protection control circuit.

Receiving section

The 144 MHz signal from the antenna passes through the helical filter (T9) and is then applied to the 1st gate of RF amplifier FET (Q6: 3SK41). The signal thus amplified is fed to the 1st gate of the mixer (Q7: 3SK41) through the band pass filter consisting of T8 and T7, where the signal is converted into the 1st IF signal of 28 MHz band. After lowering the impedance by T6, it is picked up as transverter signal.

Transmitting section

The 28 MHz band signal fed from TS-520 is converted into 144 MHz band signal through the balanced mixer consisting of Q1 and Q2 (2SK19). The signal thus converted passes through the filter circuit (T2 \sim 5). It is amplified by Q3 (3SK41) and fed to the pre-driver Q4

(2SC998), resulting to the input signal for the final unit. The transistor Q5 (2SC733) is used to control the 2nd gate voltage of Q3 (3SK41) using the protection voltage supplied from the control unit (X53-1040-00).

FINAL UNIT (X56-1150-00)

This unit amplifies the signal, from the RF unit, up to the level of the rated output power. The output of the pre-driver (Q4: 2SC998) of the RF unit passes through the tuning circuit and is power-amplified by the driver (Q1: 2SC1169), and furthermore amplified to the rated power level through the final stage power transistor (Q2: 2SC1242A). The amplified signal passes through the low pass filter (LPF) composed of L7, C12, L8 and C13 to remove the higher harmonics component, and becomes output signal.

The diodes D1 and D2 (1S1555) are used to provide each transistor with a proper bias, utilizing forward voltage to keep bias variations minimum in regard to temperature.

CIRCUIT DESCRIPTION/MODIFICATION

HET OSCILLATOR UNIT (X50-1250-00)

This is a local oscillator unit for frequency conversion. The fundamental oscillation frequency (38.666 MHz) is oscillated by Q1 (2SC535) and tripled by Q2 (2SC460) up to 116.0 MHz of local oscillation frequency. It passes through the spurious rejection filter circuit consisting of T2 and T3 and is fed to the buffer amplifier Q3 (2SC460) where the impedance is lowered to obtain necessary output.

This unit has a built-in crystal for 38.666 MHz as a standard, and is designed to obtain 117 MHz of local oscillation frequency by inserting a crystal for 39.000 MHz. Switching the band selector, this change-over is accomplished by the diode switch consisting of D1 and D2 (1N60).

CONTROL UNIT (X53-1040-00)

This unit incorporates an ALC detector circuit, protection detector circuit and RF meter circuit.

In the ALC detector circuit, the output voltage is divided by C5 (1pF) and C4 (22pF) and rectified by D2 and D3 (1N60). It is then amplified by Q1 (2SC733) to obtain ALC voltage which is feedbacked to TS-520 to control the drive voltage.

In the protection detector circuit, the reflected wave power obtained from the circuit line in parallel with the signal line and from the detector coil (L5) is rectified through D4 (1N60) for necessary output.

And in the meter circuit, the output voltage is divided and rectified by C12 (1pF) and C11 (5pF). The meter sensitivity can be adjusted by the 100 k α PC trimmer potentiomemter (VR1).

RECTIFIER/AVR UNIT (X43-1150-00)

Included in this unit are a rectifier circuit, $9 \vee$ power stabilizer circuit, $15 \vee$ power stabilizer circuit, and a relay drive circuit. The transistors Q1 and Q2 (2SD235), used to control the 9 \vee and 15 \vee stabilized power, are mounted on the heat sink of the final unit, while the transistors Q1 and Q3 (2SC733) are Darlington connected to the 9 \vee and 15 \vee stabilized power control transistors (Q1, Q2) for driving.

The transistors Q2 and Q4 (2SC733) are the error voltage detector transistors for 9 V and 15 V of power voltages, and are used for comparison with the reference voltages from D5 (WZ-090) and D6 (WZ-061). The transistor Q5 (2SC735) is the relay drive transistor and D7 (V06B) is the diode to erase the spike voltage caused by the relay.

The rectifier circuit is the bridge connected circuit using D1 \sim 4 (U05B).

Care should be used not to short the 9 V/15 V lines to the chassis, since the power stabilizer circuits are not provided with protection circuits.

CIRCUIT CHANGE

Although TS-520 works satisfactorily when only connected to TV-502, it is also designed to permit simple changes in the circuit to offer the following operating advantages:

- 1. The operating band of VHF or HF can be selected with the POWER switch on TV-502.
- 2. As the final (S2001) screen voltage of TS-520 is automatically switched, the SG switch of TS-520 may be left ON (up) position at all times.



Preparation and Precaution for Circuit Change:

- 1. Disconnect the power cord of TS-520.
- 2. Remove the case from the unit (see Fig. 2).
- 3. Short the high voltage circuit to the chassis for a short period of time using a screwdriver in order to prevent electric shock.

Method of Circuit Change:

Only the X VERTOR connector circuit may be changed. Do not touch any other circuits. To change, remove the lead wire connected between the pins 6-7 and the other lead wire connected between the pins 3-10 by referring to Fig. 4.

Be very sure that other lead wires remain as they are.

NOTE: On earlier produced TS-520, solder both the earth line of coaxial cable (A) and (B) to twelfth terminal (see Fig. 4), which are open.

After the change of the connector circuit, replace the upper lid and the bottom plate.

If TS-520 is to be operated without connecting TV-502, make sure to insert the supplied 12P shorting plug into the X VERTOR connector. Fig. 5 shows the internal connection of the 12P shorting plug.

CIRCUIT MODIFICATION

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Fig. 4 Change of TS-520 X VERTOR Connector Circuit



Fig. 5 Internal View of 12P Shorting Plug

DC Power Operation:

TV-502 can be operated on DC power. In this case, TS-520 must be equipped with DS-1. When the supplied DC power 2P plug is used, the AC-DC selector switch on the rear panel should be set to the DC position (this switch is set to "AC" when shipment) and a fuse (3A) should be provided along the DC cord.



Fig. 6 Connection of DC Plug

PARTS ALIGNMENT



PC BOARD

▼ RF (X44-1120-00)



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Q2:2SC1242A, D1,2:1S1555



PC BOARD

RECTIFIER AVR (X43-1150-00)

2000



2SC733 (Y) 2SC735 (Y)



▼ CONTROL (X53-1040-00)



Q1:2SC535(A), Q2,3:2SC460(B), D1,2:IN60





Q1: 2SC733(Y), D1~5: IN60





2SC733 (Y)



TV-502 TRANSVERTER (Overall parts list)

Ref. No.	Parts No.	Description	Re- mark
		CAPACITOR	
C1	CK45F1H103Z	Ceramic 0.01µF +80%,-209	%
C2, 3	CK45F1E403Z	Ceramic 0.04µF +80%,-209	%
C4	CE02W1E222	Electrolytic 2200µF 25WV	
C5, 6	CK45F1E403Z	Ceramic 0.04µF +80%,-20	%
C7	C90-0136-05	Electrolytic 6800µF 35WV	
C8	CK45F1H103Z	Ceramic $0.01\mu F + 80\%, -20\%$	%
C9	CC45SL2H020C	Ceramic 2pF ±0.25pF Ceramic 0.04µF +80%,-20	%
C10	CK45F1E403Z	RESISTER	/0
	BN14AB3D100J	Metal film $10\Omega \pm 5\% 2W$	
R1			
<u></u>	V11-0270-05	Diode U05B	
D1	<u> </u>	SFORMER / COIL	
	[Power transformer	- <u>T</u>
T1	L06-0032-05		
CH1	L15-0001-15	Choke coil (low frequency)	1
L1	L33-0074-05	Choke coil (heater) $(0.3\mu H)$	
L2, 3	L40-1011-03	Ferri-inductor x 2 (100 μ H)	
-	L34-0475-05		
-	L34-0476-05		
		SWITCH	
S1	S11-2022-15	Rotary switch	
S3	S04-1032-15	Rotary switch	
S4, 5	\$31-2027-05	Slide switch x 2	
	M		
-	A01-0255-02	Case (A)	
-	A01-0256-02	Case (B)	
-	A10-0413-11	Chassis	
-	A20-0888-03	Panel	
	A22-0166-13	Sub-panel	
_	A23-0549-03	Rear panel	
_	B01-0078-23	Escutcheon	
	830-0002-05	Pilot lamp (12V, 3W)	1
М	B31-0201-05	Meter	
-	B40-1096-04	Model name plate	1
	842-0545-04	Sticker (fuse)	
_	B58-0194-00	Caution card	
-	B50-1300-00	Operation manual	
	B58-0190-00	Caution card	
		(Power supply voltage) (TAG)	
-	B58-0191-00	Caution card	
		(Power supply voltage)	
-	D13-0032-03	Sprocket	
-	D16-0050-04	Chain assembly	
_	D20-0108-04	Dial shaft	
_	D32-0075-04	Switch stopper x 3	
		Dhua	
-	E03-0301-05	Plug	
J5	E04-0102-05	M type receptacle	
J6	E08-0203-25	2P connector jack	
J3, 4	E08-1208-05	12P connector socket x 2	
-	E09-0203-15	2P connector plug	
-	E09-1204-05	12P connector plug x 3	
J1, 2	E13-0101-05	1P jack x 2	
-	E14-0115-05	1P plug x 3	
-	E15-0038-05	Pilot socket	
	E19-0207-05	Plug (interchangeable)	1

Ref. No.	Parts No.	Description	Re- marks
_	E22-0216-05	Lug x 3	
-	E22-0415-05	Lug	
-	E23-0055-05	Hermetic seal	
-	E23-0069-05	Terminal (for grand cable) × 2	
-	E23-0071-04	Lug (antenna earth)	
-	E30-0019-05	Connecting cable	
_	F05-1023-05	Fuse (1A, 100V) × 2	
-	F05-5013-05	Fuse (0.5A, 220V) × 2	
-	F07-0365-04	Cover (filter case)	
	F07-0366-04	Cover (filter case)	
	F11-0211-04	Filter case	
-	F19-0184-04	Meter stopping plate	
_	J02-0049-14	Leg x 6	
-	J13-0033-15	Fuse holder	
-	J19-0452-04	Transformer retainer x 2	
-	J21-0392-04	Lead holder	
-	J32-1030-14	Round boss x 2	
-	J41-0024-15	Cord bushing	
-	J61-0014-05	Free up beit	
-	J61-0019-05	Cable wrapping band x 7	
-	K21-0267-04	Knob x 3	
-	K23-0270-04	Knob	
-	N35-3008-11	Screw x 16	
RL1	S51-4017-25	Relay	
_	H01-1275-04	Carton case	
-	H03-0387-04	Carton case (external)	
-	H10-1200-02	Buffer fixture x 2	
-	H10-1201-04	Buffer fixture	
	H20-0276-03	Protection bag	
-	H25-0016-00	Polyethyrene bag	
_	H25-0105-04	Protection bag	
_	X43-1150-00	Rectifier AVR unit	
-	X44-1120-00	RF unit	1
·	X50-1250-00	HET oscilator unit	
-	X53-1040-00	Control unit	
-	×56-1150-00	Final unit	

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RECTIFIER AVR UNIT (X43-1150-00)

Ref. No.	Parts No.	Description				Re- marks
CAPACITOR						
C1~3	CK45F1E403Z	Ceramic	0.04µF	+80%		
C4	CE04W1H4R7(RL)	Electrolytic 4.7 μ F 50WV				
C5~7	CK45F1E403Z	Ceramic	0.04µF	+80%	_20%	
RESISTOR						
R1, 2	PD14CY2E102J	Carbon	1kΩ	±5%	1/4W	
R3	PD14CY2E561J	Carbon	560Ω	±5%	1/4W	
R4	PD14CY2E102J	Carbon	1kΩ	±5%	1/4W	
R5	PD14CY2E123J	Carbon	12kΩ	±5%	1/4W	
R6	PD14CY2E102J	Carbon	1kΩ	±5%	1/4W	
R7	PD14CY2E391J	Carbon	390 <i>Ω</i>	±5%	1/4W	
R8	PD14CY2E152J	Carbon	1.5k Ω	±5%	1/4W	
R9	PD14CY2E103J	Carbon	10kΩ	±5%	1/4W	

Ref. No.	Parts No.	Description	Re- marks			
	SEMICONDUCTOR					
Q1~4	V03-0123-05	Transistor 2SC733 (Y)				
$D1 \sim 4$	V03-0241-09 V11-0270-05	Transistor 2SC735 (Y)				
	V11-0240-05	Diode U05B Zener diode WZ-090				
D6	V11-0243-05	Zener diode WZ-061	-			
D7	V11-0219-05	Diode V06B				
	PO	TENTIOMETER				
VR1	R12-1020-05	Volume 1kΩ				
VR2	R12-0042-05	Volume 500Ω				
	MIS	CELLANEOUS	(
_	E23-0047-04	Terminal x 17				
-	J25-1146-04	PC board				

RF UNIT (X44-1120-00)

	Ref. No.	Parts No.	Description			Re- marks
		C	APACITO	R		un : ,,,,,,
	C1 C2	CC45SL1H330J CC45CH1H100J	Ceramic	33pF	±5% ±5%	
	C2 C3	CC45CH1H220J	Ceramic	10pF	±5%	
	C3 C4	CC45CH1H270J	Ceramic Ceramic	22pF	±5%	
. 1	C5, 6	CC45SL1H330J	Ceramic	27pF	±5%	
	C3, 8	CC455L1H3305	Ceramic	33pF 7p5	±0.5pF	
Í	C8, 9	CC45D1H102M	Ceramic	7pF	±20%	
	C10	CK45F1H103ZTP	Ceramic	0.001µF		
	C10	CC45SL1H070D	Ceramic	0.01µF 7pF	+80%,20% ±0.5pF	
	C12	CC45CH1H070D	Ceramic	7pF 7pF	±0.5pF	
	C12	C90-0231-05	Ceramic	0.5pF	±0.5pF	
	C14	CC45CH1H120J	Ceramic	12pF	±5%	
	C15	C90-0231-05	Ceramic	0.5pF	±0.5pF	
	C16	CC45CH070D	Ceramic	7pF	±0.5pF	
	C17	CC45SL1H101J	Ceramic	100pF	±5%	
	C18~21	CK45F1H103ZTD	Ceramic	0.01µF	+80%,-20%	
	C22	CK45D1H102M	Ceramic	0.001µF	±20%	
	C23, 24	CK45F1H103ZTD	Ceramic	0.01µF	+80%,-20%	
	C25	CC45SL1H470J	Ceramic	470pF	±5%	
	C26~28	CK45D1H102M	Ceramic	0.001µF	±20%	
	C29	CC45SL1H100D	Ceramic	10pF	±0.5pF	
	C30, 31	CK45F1H103ZTD	Ceramic	0.01µF	+80%,-20%	
	C32	CC45SL1H330J	Ceramic	33pF	±5%	
	C33	CK45F1H103ZTD	Ceramic	0.01µF	+80%,20%	
	C34	CC45CH1H270J	Ceramic	27pF	±5%	
	C35	CK45F1H103ZTD	Ceramic	0.01µF	+80%,-20%	
	C36	CC45CH1H220J	Ceramic	22pF	±5%	
	C37	CK45F1H103ZTD	Ceramic	0.01µF	+80%,20%	
	C38	CC45SL1H330J	Ceramic	33pF	±5%	
	C39	CK45F1H103ZTD	Ceramic	0.01µF	+80%,—20%	
	C40	CC45SL1H100D	Ceramic	10pF	±0.5pF	
	C41	CC45CH1H050D	Ceramic	5pF	±0.5pF	
	C42	CC45SL1H030D	Ceramic	3pF	±0.5pF	
	C43	CC45CH1H070D	Ceramic	7pF	±0.5pF	
	C44~49	CK45D1H102M	Ceramic	0.001µF	±20%	
à	C50	CK45F1H103Z	Ceramic	0.01µF	+80%,20%	
1	C51	CK45F1E403Z	Ceramic	0.04µF	+80%,-20%	l l
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Ref.'No.	Parts No.	Description Re- marks				
	I	RESISTO	R			Indiks
R1, 2	PD14CY2E103J	Carbon	10kΩ	±5%	1/4W	<u> </u>
R3	PD14CY2E222J	Carbon	2.2kΩ	±5%	1/4W	1
R4	PD14CY2E122J	Carbon	1.2kΩ	±5%	1/4W	1
R5	PD14CY2E474J	Carbon	470kΩ	±5%	1/4W	
R6	PD14CY2E822J	Carbon	8.2kΩ	±5%	1/4W	
R7	PD14CY2E102J	Carbon	1kΩ	±5%	1/4W	
R8	PD14CY2E104J	Carbon	100kΩ	±5%	1/4W	
R9 R10	PD14CY2E101J PD14CY2E102J	Carbon	100Ω 150	±5%	1/4W	
R11	PD14CY2E470J	Carbon Carbon	1kΩ 47Ω	±5% ±5%	1/4W 1/4W	
R12	PD14CY2E101J	Carbon	47 <i>31</i> 100Ω	±5%	1/4W	
R13	RC05GF2H223J	Carbon	22kΩ	-5%	1/2W	
R14	RN14AB3D104J		m 100kΩ	±5%	2W	
R15	PD14CY2E472J	Carbon	4.7kΩ	±5%	1/4W	
R16, 17	PD14CY2E101J	Carbon	100Ω	±5%	1/4W	
R18, 19	PD14CY2E104J	Carbon	100kΩ	±5%	1/4W	
R20	PD14CY2E101J	Carbon	100Ω	±5%	1/4W	
R21	PD14CY2E392J	Carbon	3.9kΩ	±5%	1/4W	
R22	PD14CY2E101J	Carbon	100Ω	±5%	1/4W	
R23	PD14CY2E104J	Carbon	100kΩ	±5%	1/4W	
R24	PD14CY2E222J	Carbon'	2.2kΩ	±5%	1/4W	
R25 R26	PD14CY2E682J	Carbon	6.8kΩ	±5%	1/4W	
R25 R27, 28	PD14CY2E821J PD14CY2E101J	Carbon Carbon	820Ω 100Ω	±5% ±5%	1/4W 1/4W	
				//	17 -+ VV	
Q1, 2	V09-0012-05					
Q1, 2 Q3	V09-0012-05 V09-0057-05	FET 2SK FET 3SK				
Q3 Q4	V03-0168-05		or 2SC998			
Q5	V03-0123-05		or 3SC733	(Y)		
Q6, 7	V09-0057-05	FET 3SK		•		
D1	V11-0243-05		ode WZ-06	1		
D2	V11-0263-05	Diode 1S	1555			
		COIL				
Τ1	L31-0348-05		oil (28 MH	łz)		
Т2	L31-0349-05	Tuning c				
тз	L31-0350-05		oil (144 M			
Т4 ТБ	L31-0266-05	-	oil (144 M			
Т5 Т6	L31-0267-05 L31-0348-05	-	oil (144 M			
тъ т7, 8	L31-0348-05 L31-0350-05		oil (28 MF oil (144 M			
ту, 8 Т9	L31-0350-05 L79-0022-05	Helical fi	oil (144 M Iter	. 14/		
T10	L31-0266-05		oil (144 M	Hz)		
L1	L40-1011-03	-	uctor (100			
L2	L34-0388-05	VHF coi				
L3	L34-0432-05	VHF coi				
L4, 5	L34-0430-05	VHF coi	I			
L6	L34-1511-03	Ferri-ind	uctor (150)μH)		
	VARIABLE CAP	ACITOR	/ TRIMMI	ER		
VC1,2	C01-0166-15	Variable	capacitor	(29P x	4)	
TC1	C05-0030-15	Ceramic	trimmer (2	20PF)		
тс2,3	C05-0015-15	Ceramic	trimmer (4	10PF)		<u> </u>
	POTE	NTIOME	TER			
VR1	R12-0042-05	Volume				
VR2	R12-4016-05					
	I	ELLANE				r
-	D13-0032-03	Sprocket				
	E23-0047-04	Terminal	x 17			
	J25-1147-03	PC boarc	1			
					=	11

HET UNIT (X50-1250-00)

Ref. No.	Parts No,	Description			
	C	APACITO	R		marks
C1, 2	CC45SL1H050D	Ceramic	5pF	±0.5pF	Γ
C4, 5	CK45F1H103Z	Ceramic		+80%, -20%	
C7	CK45D1H102M	Ceramic	0.001µF	±20%	
C8	CC45SL1H330J	Ceramic	33p F	±5%	
C9	CC45TH1H390J	Ceramic	39 p F	±5%	
C10	CK45F1H103Z	Ceramic	0.01µF	+80%, -20%	
C11	CC45SL1H221J	Ceramic	220pF	±5%	
C12	CK45F1H103Z	Ceramic	0.01µF	+80%,20%	1
C13	CC45CH1H150J	Ceramic	15pF	±5%	1
C14	CK45F1H103Z	Ceramic	0.01µF	+80%, -20%	
C15	C90-0231-05	Ceramic	0.5pF	+80%, -20% ±5%	1
C16	CC45CH1H120J	Ceramic	12pF 15p5	±5%	
C17	CC45SL1H150J CK45D1H102M	Ceramic Ceramic	15pF 0.001µF		1
C18,19 C20	CK45F1H103Z	Ceramic	0.001µF	+80%, -20%	
		RESISTO		10078, -2078	1
R1, 2	PD14CY2E473J	Carbon	47kΩ	±5% 1/4W	<u> </u>
R4	PD14CY2E101J	Carbon	100Ω	±5% 1/4W	
R5	PD14CY2E470J	Carbon	47Ω	±5% 1/4W	
R6	PD14CY2E101J	Carbon	100Ω	±5% 1/4W	
R8	PD14CY2E102J	Carbon	1kΩ	±5% 1/4W	1
R9	PD14CY2E273J	Carbon	27kΩ	±5% 1/4W	
R10	PD14CY2E682J	Carbon	6.8kΩ	±5% 1/4W	
R11	PD14CY2E102J	Carbon	1kΩ	±5% 1/4W	
R12	PD14CY2E101J	Carbon	100Ω	±5% 1/4W	
R13	PD14CY2E103J	Carbon	10kΩ	±5% 1/4W	
R14	PD14CY2E104J	Carbon	100kΩ	±5% 1/4W	
R15	PD14CY2E100J	Carbon	10Ω	±5% 1/4W	
R16	PD14CY2E101J	Carbon	100Ω	±5% 1/4W	
R17 R18	PD14CY2E220J	Carbon Carbon	220Ω 47kΩ	±5% 1/4W ±5% 1/4W	
R 10	PD14CY2E473J SEM	ICONDUC		- 5% 1/4**	i
Q1	V03-0104-05	ſ	or 2SC535	(A)	<u> </u>
02,3	∨03-0079-05		r 2SC460		
D1, 2	V11,0551-05	Diode 1N			
	COIL /	X'tal / TR	IMMER		
Т1	L32-0182-05	Oscillatio			T
Т2, 3	L31-0267-05	Tuning c			
L1,2	L40-1511-03		uctor (150		
L4	L40-1511-03	1	uctor (150		
L5,6	L40-1011-03		uctor (100	•	
X1 X2	L77-0401-05 L77-0409-05		scillator (3 scillator (3	38.666 MHz)	
<u>^</u>	277-0409-05	OPTION		UT14/	
TC1, 2	C05-0029-15	Ceramic			
	l	CELLANE			1
_	E18-0201-05	Crystal so	ocket		
-	E23-0047-05	Terminal			
-	J25-1148-09	PC board			

CONTROL UNIT (X53-1040-00)

Parts No.							
	Description				Re- marks		
C	ΑΡΑCΙΤΟ	R					
CK45D1H102M	Ceramic	0.001µF	±20%				
CC45SL2H220J			±5%				
CC45SL2H010C							
CE04W1H4R7(RL)	Electrolytic 4.7µF 50WV						
CE04W1HR47(RL)	Electroly	tic 0.47µF	50W				
CK45D1H102M	Ceramic	0.001µF	±20%				
CC45SL2H050C	Ceramic	5pF	±0.25	рF			
CC45SL2H010C	Ceramic	1pF	±0.25	рF			
CK45D1H102M	Ceramic	0.001µF	±20%				
RESISTOR							
PD14CY2E103J	Carbon	10kΩ	±5%	1/4W			
PD14CY2E104J	Carbon	100kΩ	±5%	1/4W			
PD14CY2E472J	Carbon	4.7kΩ	±5%	1/4W			
PD14CY2E222J	Carbon	2.2kΩ	±5%	1/4W			
PD14CY2E823J	Carbon	82kΩ	±5%	1/4W			
PD14CY2E153J	Carbon	15kΩ	±5%	1/4W			
SEMI	CONDUC	TOR					
V03-0123-05	Transisto	r 2SC733 (Y)				
∨11-0051-05	Diode 1N	60					
	COIL						
L40-1011-03	Ferri-indu	uctor (100)	иH)				
L33-0025-05	Choke co	il (1µH)					
L40-1011-03	Ferri-indu	uctor (100)	uΗ)				
L39-0052-05	Detecting	coil					
POTE	ENTIOME	TER					
R12-5014-05	Volume 1	00kΩ					
R12-4016-05	Volume 5	iOkΩ					
R12-0042-05	Volume 5	Ω00					
MISC	CELLANE	ous			·		
E23-0047-04	Terminal	x 10					
J25-1149-14	PC board						
	CK45D1H102M CC45SL2H220J CC45SL2H20J CC45SL2H010C CE04W1H4R7(RL) CK45D1H102M CC45SL2H050C CC45SL2H050C CC45SL2H010C CK45D1H102M PD14CY2E103J PD14CY2E103J PD14CY2E104J PD14CY2E104J PD14CY2E222J PD14CY2E222J PD14CY2E223J PD14CY2E153J SEMI V03-0123-05 V11-0051-05 L40-1011-03 L33-0025-05 L40-1011-03 L39-0052-05 POTE R12-5014-05 R12-4016-05 R12-0042-05 MISC E23-0047-04	CK45D1H102M Ceramic CC45SL2H220J Ceramic CC45SL2H010C Ceramic CC45SL2H010C Ceramic CE04W1H4R7(RL) Electroly CC45SL2H050C Ceramic CC45SL2H050C Ceramic CC45SL2H050C Ceramic CC45SL2H050C Ceramic CC45SL2H010C Ceramic CC45SL2H010C Ceramic CC45SL2H010C Ceramic CK45D1H102M Ceramic CK45D1H102M Carbon PD14CY2E103J Carbon PD14CY2E323J Carbon PD14CY2E323J Carbon PD14CY2E323J Carbon PD14CY2E33J Carbon PD14CY2E33J Carbon PD14CY2E305 Transiston V03-0123-05 Diode 1N COIL L40-1011-03 L40-1011-03 Ferri-indu L30-0052-05 Choke co L40-1011-03 Ferri-indu L30-0052-05 Volume 1 R12-4016-05 Vo	CC45SL2H220J Ceramic 22pF CC45SL2H010C Ceramic 1pF CE04W1H4R7(RL) Electrolytic 4.7μF CE04W1HR47(RL) Electrolytic 0.47μF CC45SL2H050C Ceramic 5pF CC45SL2H010C Ceramic 0.001μF CC45SL2H050C Ceramic 0.001μF CC45SL2H010C Ceramic 0.001μF CC45SL2H010C Ceramic 0.001μF CK45D1H102M Ceramic 0.001μF CK45D1H102M Ceramic 0.001μF CK45D1H102M Carbon 10kΩ PD14CY2E103J Carbon 100kΩ PD14CY2E103J Carbon 2.2kΩ PD14CY2E32J Carbon 82kΩ PD14CY2E153J Carbon 15kΩ PD14CY2E153J Carbon 15kΩ V03-0123-05 Transistor 2SC733 (Diode 1N60) V03-0123-05 Transistor 2SC733 (Diode 1N60) V03-0123-05 Choke coil (1μH) L40-1011-03 Ferri-inductor (100) L39-0052-05 Choke coil (1μH) L40-1011-03 Ferri-inductor (100) L39-0052-05 Volume 100kΩ R12-4016-05 Volume 500Ω	CK45D1H102M Ceramic 0.001μ F $\pm 20\%$ CC45SL2H220J Ceramic $22p$ F $\pm 5\%$ CC45SL2H010C Ceramic $22p$ F $\pm 5\%$ CE04W1H4R7(RL) Electrolytic 4.7μ F $50W$ CC45SL2H050C Ceramic $5p$ F ± 0.25 CC45SL2H050C Ceramic $5p$ F ± 0.25 CC45SL2H010C Ceramic $5p$ F ± 0.25 CC45SL2H010C Ceramic $10p$ F ± 0.25 CK45D1H102M Ceramic $10p$ F ± 0.25 CK45D1H102M Ceramic $10p$ F ± 0.25 CK45D1H102M Carbon $10k\Omega$ $\pm 5\%$ PD14CY2E103J Carbon $10k\Omega$ $\pm 5\%$ Carbon $2k\Omega$	CK45D1H102M Ceramic 0.001μ F $\pm 20\%$ CC45SL2H220J Ceramic $22p$ F $\pm 5\%$ CC45SL2H010C Ceramic $1p$ F $\pm 0.25p$ F CE04W1H4R7(RL) Electrolytic 4.7μ F $50WV$ CE04W1HR47(RL) Electrolytic 0.47μ F $50WV$ CC45SL2H050C Ceramic $5p$ F $\pm 0.25p$ F CC45SL2H010C Ceramic $1p$ F $\pm 0.25p$ F CC45SL2H010C Ceramic 0.001μ F $\pm 20\%$ CC45SL2H010C Ceramic 0.001μ F $\pm 20\%$ CK45D1H102M Carbon $10k\Omega$ $\pm 5\%$ $1/4W$ PD14CY2E103J Carbon $10k\Omega$ $\pm 5\%$ $1/4W$ PD14CY2E104J Carbon $10k\Omega$ $\pm 5\%$ $1/4W$ PD14CY2E323J Carbon $2.2k\Omega$ $\pm 5\%$ $1/4W$ PD14CY2E153J Carbon $15k\Omega$ $\pm 5\%$ $1/4W$ V03-0123-05 Transistor $2SC733$ (Y) Diode $1N60$ V11-0051-		

FINAL UNIT (X56-1150-00)

Ref. No.	Parts No.		Re- marks		
	C	APACITO	R		
C1	CC45SL2H070D	Ceramic	7pF	±0.5pF	
C2	CC45SL2H100J	Ceramic	10pF	±5%	
C3	CK45D1H102M	Ceramic	0.001µF	±20%	
C4	CK18E2H102P	Ceramic	0.001µF	+100%,—0%	
C5, 6	C90-0117-05	Ceramic	0.001µF	+100%,—0%	
C7	CK45D1H102M	Ceramic	0.001µF	±20%	
C8	CC45SL2H470J	Ceramic	47pF	±5%	
C9	CC45SL2H330J	Ceramic	33pF	±5%	
C10,11	CK45D1H102M	Ceramic	0.001µF	±20%	
C12	CC45SL2H270J	Ceramic	27pF	±5%	
C13	CC45SL2H070D	Ceramic	7pF	±0.5pF	
C14	C90-0117-05	Ceramic	0.001µF	±0.5pF	
C15	CK18E2H102P	Ceramic	0.001µF	+100%,—0%	

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Ref. No.	Parts No.	Description	Re- marks	Ref. No,	Parts No.
		RESISTOR			
R1	RC05GF2H330J	Carbon 33Ω ±5% 1/	'2W		
R2	RC05GF2H681J		2W		
R3	PC05GF2H220J		2W		
R4	RC05GF2H121J		2W		
R5	RC05GF2H221J		2W		
R6	RN14AB3D151J	Carbon 150Ω ±5% 2V			
	SEN	ICONDUCTOR			
Q1	V03-0350-05	Transistor 2SC1169			
Q2	V03-0349-05	Transistor 2SC1242A			
Q3, 4	V04-0046-05	Transistor 2SD235 (Y)			
D1, 2	∨11-0076-05	Diode 1S1555			
	CO	L / TRIMMER			
L1	L34-0426-05	VHF coil			
L2	L34-0464-05	VHF coil			
L4	L33-0074-05	Heater choke (0.3 μ H)			
L5	L34-0378-05	VHF coil			
L6	L34-0465-05	VHF coil			
L7	L34-0466-05	VHF coil			
L8 TC1,2	L34-0467-05	VHF coil			
тсз	C05-0013-15 C05-0057-05	Ceramic trimmer (20PF)			
TC4	C05-0060-05	Ceramic trimmer (20PF)			
		Ceramic trimmer (45PF)			
_	E23-0001-05	CELLANEOUS			
	223-0001-05	Hermetic seal x 2			
-	F01-0198-04	Heat sink			
-	F07-0358-14	Final cover			
-	F10-0358-04	Shield plate (final)			
-	F11-0205-04	Shield case (final)			
-	F20-0078-05	Insulating plate x 2			
-	J25-1150-04	PC board			
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Remarks

Description

TROUBLESHOOTING

RECEIVING SECTION

SYMPTOM	CAUSE	REMEDY
1. No power supply is available.	 Blown fuse Defective power switch Disconnection near plug 	 Replace Check and replace Check power cord
2. Blown fuse	 Defective rectifier diode U05B of Rectifier AVR unit (X43-1150-00) 15 Volt B circuit shorted to chassis 	 Replace Check and rewire
3. Too low sensitivity	 Disconnection or short circuit of connecting wire Defective FET Q6, Q7 of RF unit (X44- 1120-00) Poor adjustment of tuning circuit of RF unit (X44-1120-00) Defective D6 (WZ061) of RF unit (X44- 1120-00) Poor adjustment of Helical resonator Poor contact of relay 	 Check and replace Replace Readjust T6, T7, T8, T9 Replace Readjust Replace
4. No receiver noise	 Poor adjustment of oscillating coil of HET oscillator unit (X50-1250-00) Defective diode switch of HET oscillator unit (X50-1250-00) Poor contact of band-switch of HET oscillator unit (X50-1250-00) Disconnection of output coaxial cable Disconnection of antenna circuit or IF output coaxial cable 	 Readjust Replace Check contact Check contact Check and rewire

TRANSMITTING SECTION

SYMPTOM	CAUSE	REMEDY
1. No output	 Defective Q1, Q2 of Final unit (X56-1150-00) Defective Q1, Q2, Q3, Q4, Q5 of RF unit (X44-1120-00) 	o Replace o Replace
	 3) Poor adjustment of oscillating coil of HET oscillator unit (X50-1250-00) 	o Readjust
	4) Disconnecting of input or output coaxial cable	 Check contact and rewire
	5) Poor adjustment of VR3 of Control unit (X53- 1040-00)	o Readjusť
	6) Poor contact of relay	o Replace
	 Disconnecting or short circuit of connecting cord 	o Check and replace
2. Low output	 Poor adjustment of trimmer capacitor of Final unit (X56-1150-00) 	o Readjust
	 Poor tuning of tuning circuit of RF unit (X44-1120-00) 	 Readjust
	3) Poor adjustment of T2, T3 of HET oscillator unit (X50-1250-00)	o Readjust
	4) Poor adjustment of VR2, VR3 of control unit (X53-1040-00)	o Readjust
	5) Defective Q1, Q3, D5, D6 of Rectifier AVR unit (X43-1150-00)	o Replace
3. Too high or too low deflection of RF meter	1) Poor adjustment of VR1 of Control unit (X53- 1040-00)	o Readjust
4. No deflection of RF meter	1) Defective D1, D5 of Control unit (X53-1040- 00)	o Replace
5. Too high deflection of ALC meter due to undesirable high power output	 Poor adjustment of V R2 of Control unit (X53- 1040-00) 	o Readjust
6. Too low deflection of ALC meter due to extremely low output	1) Disconnection of connecting cable	 Check conduction and refer to 2. Low output
7. Stand-by function is inoperative	1) Relay does not work	 Check and replace Q5 of Recti- fier AVR unit (X43-1150-00), connecting cable and connector
	 Relay keeps working position unnecessarily, although switch is turned off. 	o Check and replace Q5 of Recti- fier AVR unit (X43-1150-00)

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ADJUSTMENTS

Adjustments of TV-502 should be performed with TS-520 connected as shown in Fig. 7.



Fig. 7 Connection

RECEIVING SECTION

Fig. 8 shows the level diagram of reception.

NOTE 1: As shown in Fig. 8, the SSG signal of 145.0 MHz 0dB is fed from the ANT terminal and the AF VR is adjusted for the audio output of $0.63 \text{ V/8}\Omega$. When the AF VR is properly adjusted for the specified audio level, the SSG signal level indicated at each section should be obtained.

NOTE 2: Measurement of SSG output should be made through a ceramic capacitor of $0.01\mu F$ (50 WV).

1. Rectifier/AVR Unit (X53-1150-00)

- (1) Test equipment
- 1) Voltmeter (tester)
- (2) Adjustments (Fig. 10)
- 1) 15 V Setting

With the power switch turned to ON, connect a DC voltmeter to the terminal (14) on the AVR unit.

Adjust VR1 for 15 V on the voltmeter.

2) 9 V Setting

Connect the DC voltmeter to the terminal (9) on the AVR unit. Adjust VR2 for 9 V on the voltmeter

2. Heterodyne Oscillator Unit (X50-1250-00)

- (1) Test equipment
- 1) RF VTVM (f: 150 MHz or higher)
- 2) Frequency Counter (f: 150 MHz or higher)
- (2) Adjustment (Fig. 10)
- Adjustment of Oscillating Level Connect the RF VTVM to the OUT terminal on the heterodyne unit. Turn the core of T1 so that the output is set at 1dB down position from the peak point. This adjustment should be performed using an insulated screwdriver. Next, adjust T2 and T3 for maximum reading on VTVM.

Repeat the above adjustment two or three times.



Fig. 8 Level Diagram of Reception



Fig. 9 Level Diagram of Transmission

ADJUSTMENTS

- 2) Check of Vacant Channel (X2) Output Insert a 39 MHz crystal into the crystal socket (X2) and set the BAND switch to ''145 MHz'' to check that the crystal is oscillating. After checking, remove the crystal and set the BAND switch back to ''144 MHz''.
- Adjustment of Heterodyne Frequency Disconnect the VTVM and connect the frequency counter instead. Adjust TC1 for 116 MHz of frequency. Then set TC2 in the mechanical center position.





Heterodyne unit (X50-1250-00) Fig. 10

3. RF Unit (X44-1120-00)

- (1) Test equipment
- SSG (f: 144 ~ 148 MHz, modulation not required)
- 2) Oscilloscope
- 3) AF VTVM
- (2) Adjustment Before adjustments, set the switches and knobs on TV-502 as follows:

TV-502

Front Panel:	
POWER switch	ON
BAND switch	144
IN TUNE knob	Center position
PRESELECTOR knob	Center position
Rear Panel:	
AC-DC selector switch	AC
2m ONLY-6m CONNECT	•
selector switch	2m ONLY

- 144.5 MHz Sensitivity Adjustment Set the band switch on TS-520 to "28.5 MHz". Then set the VFO dial to "0" and the mode switch to "USB". Apply the signal of 144.5 MHz 60dB from SSG to the antenna terminal on TV-502. Adjust the VFO knob and DRIVE knob for maximum reading on the S meter. Then adjust T6 in the RF unit until the S meter of TS-520 indicates maximum deflection.
- 2) 145 MHz Sensitivity Adjustment

Set the VFO dial to "0" (29 MHz) and apply the 145 MHz signal of SSG. Adjust the DRIVE knob on TS-520 for maximum sensitivity. Next, adjust the IF TUNE knob on TV-502 for maximum reading on the S meter. Also, adjust T7 and T8 in the RF unit until maximum sensitivity is obtained. The adjustment should be repeated two or three times. Note that the signal level of SSG should be lowered properly according to the increase of the sensitivity. Then obtain a maximum reading on the S meter by adjusting the air-core coil of the helical filter.

NOTE: The PRESELECTOR knob should set in its center position.

3) 144 MHz Sensitivity Adjustment

Set the band switch on TS-520 to "28 MHz". Then set the VFO dial to "0" and apply the 144 MHz signal from SSG. Adjust TS-520 for maximum sensitivity. To obtain maximum reading on the S meter, turn the IF TUNE knob on TV-502. The maximum sensitivity can be obtained by adjusting the 3 cores of T9 from the rear of the printed circuit board.

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ADJUSTMENTS



Fig. 11 RF Unit (X44-1120-00)

TRANSMITTING SECTION:

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Fig. 9 shows the transmission level diagram.

NOTE: The levels indicated in Fig. 9 were measured with RF VTVM having input capacitance of less than 3pF in the condition CW output of 9 W during AC operation

1. Preparation for Adjustment

- (1) Test equipment
- 1) DC power supply (12-16 V adjustable, 2A min.)
- 2) RF VTVM
- 3) 50 Ω terminated power meter
- 4) DC voltmeter (tester)
- 5) SSG
- (2) Adjustment

Before making adjustments, the switches and knobs on TV-502 and TS-520, and the semifixed resistors in the RF unit and control unit. should be set as follows:

TV-502

FRONT PANEL	
POWER Switch	ON
BAND Switch	144
IF TUNE Knob	Center position (or maxi- mum receiving sensitivity)
PRESELECTOR Knob	Center position (or maxi- mum receiving sensitivity)
REAR PANEL	
AC-DC Selector Switch	DC
2m ONLY-6m CONNECT Selector Switch	2m ONLY

TS-520

FRONT PANEL	
MODE Switch	CW
H.SW Switch	ON
CAR Knob	Center position
REAR PANEL	
SG Switch	OFF

RF unit (X44-1120-00) VR2 Maximum clockwise Control unit (X53-1040-00)

VR2 Maximum clockwise The adjustment of transmitter section should preferably be made with a DC power stabilizer for observing the current consumption (power supply voltage of 12 V).

2. Adjustment of RF Unit (X44-1120-00)

- (1) Set the band switch on TS-520 to "28.5" and the VFO dial to "500". Connect the RF VTVM to the DRV terminal on the RF unit and set the standby switch on TS-520 to "SEND".
- (2) Adjust the DRIVE knob on TS-520 and also adjust T1 \sim 5, TC1 and TC2 in the RF unit of TV-520 so that a maximum reading is obtained on the RF VTVM.

3. Power Adjustment

- (1) Maintaining power supply voltage of 12 V, disconnect the RF VTVM. Adjust T3 in the RF unit and TC1 and TC2 in the final unit for maximum current (Fig. 14).
- (2) With TC3 and TC4 in the final unit set to the positions shown in Fig. 12(A), fine adjust so that a maximum power is obtained.

NOTE: Care should be taken in adjustment because TC3 and TC4 are also tuned in the positions shown in Fig. 12(B).



Fig. 12

- (3) Next, set the power voltage to 15 V. Fine adjust TC3 in the RF unit and TC1 and TC2 in the final unit for maximum current.
- (4) Readjust TC3 and TC4 in the final unit to obtain maximum power. This adjustment should be repeated two or three times.

NOTE: TC4 should be set in such a position that the current begins to decrease while the output power remains unchanged

- (5) Set the band switch on TS-520 to "28" and the VFO dial to "500". The IF TUNE knob on TV-502 should be in its center position.
- (6) Adjust the DRIVE knob on TS-520 until the ALC meter causes maximum deflection and then adjust T1 in the RF unit for maximum current.

- (7) Under the above condition, set the AC-DC selector switch on the rear panel to "AC". Then, adjust VR2 of the control unit until the output power reaches 9 W (ALC adjustment) (Fig. 15).
- (8) Turn VR1 of the control unit so that the RF meter indicates the point "8" (RF meter adjustment). Then, set the AC-DC selector switch back to "DC".

4. Readjustment of RF Unit

- (1) Set the band switch on TS-520 to "28.5" with the VFO dial remaining in "500" position.
- (2) Turn the DRIVE knob on TS-520 and the IF TUNE knob on TV-502 until the ALC meter on TS-520 causes maximum deflection.
- (3) Fine adjust T2 \sim T5, TC1 and TC2 in the RF unit of TV-502 for maximum reading on the ALC meter. This adjustment should be repeated several times.

NOTE: This adjustment must be made carefully because it largely relates to the supurious radiation.

5. Protection Adjustment

- (1) Connect the "minus" lead of a voltmeter to the -6 terminal of the control unit (X53-1040-00) and the "plus" lead to the PRO terminal. Adjust VR3 in the control unit for minimum reading on the voltmeter.
- (2) Disconnect the leads of the voltmeter, set VR2 in the RF unit to the center position and remove the cord of the power meter (antenna open circuited). Adjust VR2 in the RF unit so that the current flow reaches 1A.

NOTE: This adjustment should be performed quickly.



Fig. 13 RF unit (X44-1120-00)

ADJUSTMENTS



6. Trap Adjustment

- (1) Set the band selector switch to "145". Remove the pin cord from the 2m TX IN terminal and connect SSG to feed 148 MHz 100 dB signal.
- (2) Connect RF VTVM to the gate of Q1 in the RF unit and adjust T1 for minimum reading on VTVM

NOTE 1: The series trap consisting of T10 and C2 is used to remove the fourfold harmonics (37 MHz x 4 = 148 MHz) of the frequency of the 28 MHz heterodyne oscillator in TS-520. It protects TS-520 against the near-by spurious radiation.

NOTE 2. If expected effect cannot be attained by adjusting the trap, readjust the heterodyne oscillator coil in TS-520.



Fig. 14 Final unit (X56-1150-00)



Fig. 15 Control unit (X53-1040-00)



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ADJUSTMENTS/REFERENCE

Replacement of Transistors in Final Unit:

The final unit uses two transistors. One is Q1 (2SC1169) in the driver circuit and the other is Q2 (2SC1242A) in the power amplifier circuit at the final stage. To replace these transistors, remove the case and follow the procedure shown in the illustration (see Fig. 16).



Fig. 16 Replacement of Final Unit Transistors

*REFERENCE

- 1. Connection of TV-502 to TS-520 and Precaution for Operation
 - (1) Fig. 17 shows the method of connecting TV-502 to TS-520.



If the circuit of TS-520 has already been changed as described previously, it is possible to start 2m operation with the SG switch on TS-520 and the HF antenna left as they are. For HF operation, simply set the power switch of TV-502 to OFF.

If the modified TS-520 is to be used alone, be sure to insert the 12P shorting plug supplied with TV-502.

(2) For 2m operation, if TV-502 is connected to TS-520 whose circuit is not changed, make certain that the SG switch is set to OFF and the HF antenna is removed. For HF operation under such a condition, be sure to disconnect the pin cord plug from the X VERTER IN terminal on TS-520 (For decrease of receiving sensitivity might happen.)

2. Method of Reducing 2m Band Near-by Suprious radiation (TS-520)

When the transverter is connected for 2m operation. the HF unit (TS-520) may sometimes become a cause of suprious radiation (near-by suprious during transmission). While TS-520 is designed to fully meet with the requirements of HF band, it has been done in the circuit starting with No. 05 production lot that only the 28 MHz band is improved to less than -50 dB to satisfy the requirement (less than -60 dB) of the 2m band specified in the ELECTRIC WAVE LAW.

The suprious radiation in 2m band can be further reduced by making readjustments as follows: NOTE: Refer to the Technical Service Information (Bo-

Ho-205) for the above improvement in TS-520.

Adjusting Method:

- (1) Adjust each knob on TS-520 and TV-502 for maximum power in 144.8 MHz (28.8 MHz for TS-520) MODE CW.
- (2) Obtain maximum reading on the ALC meter by adjusting the semi-fixed resistor VR11 on the lug in the IF unit of TS-520.
- (3) Receive a signal around 144,585 MHz using another receiver and readjust VR11 (TS-520) for minimum reading on the S meter (another receiver). In the level where the S meter causes no deflection, readjustment should also be made for minimum AF output (TS-520).

3. Method of Improving Near-by Suprious radiation and second harmonics (TV-502)

(1) Final unit

Position of TC4 (for improving second harmonics)



Turn to increase capacity from center position.

Turn to decrease capacity from center position.

(2) RF unit

1) Position of TC3 (for improving of suprious of 116 MHz local oscillator)

Set TC3 to the point C1 on the following fiqure.



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REFERENCE



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SCHEMATIC DIAGRAM

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